

## Model RFP-100200-4X50-2





#### **Features**

- DC 3.0 GHz
- 30 Watts
- **BeO** Ceramic
- Non-Nichrome Resistive Element
- Low VSWR
- 100% Tested

**Outline Drawing** 

# Chip Terminations 30 Watts, 50 $\Omega$

#### **General Specifications**

**Resistive Element:** Substrate: **Terminals:** 

Thick film Beryllium oxide ceramic Thick film silver

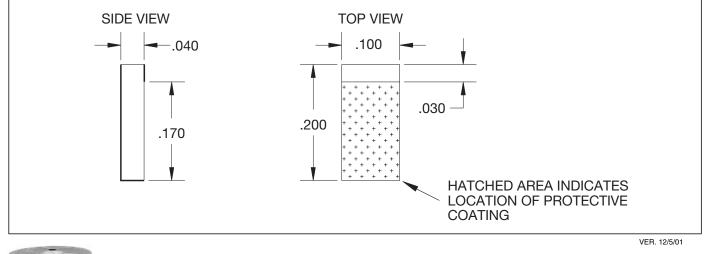
#### **Electrical Specifications**

**Resistance Value: Frequency Range:** Power: V.S.W.R.:

50 ohms, ±2% DC - 3.0 GHz 30 Watts 1.25:1

Notes: Tolerance is ±.010, unless otherwise specified. Operating temperature is -55°C to +150°C (see chart). Designed to meet or exceed applicable portions of MIL-E-5400. All dimensions are in inches.

Specifications subject to change without notice.



Available on Tape and Reel for Pick and Place Manufacturing.

Sales Desk USA: Voice: (800) 544-2414 Fax: (315) 432-9121 Sales Desk Europe: Voice: (+44) 23 92 232392 Fax: (+44) 23 92 251369

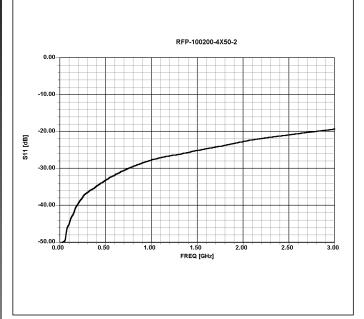


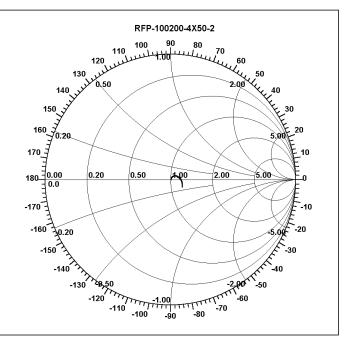
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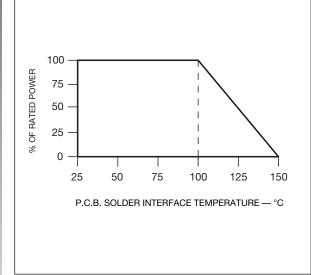
**RF Power** 

### **Typical Performance**

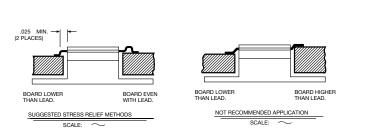




#### **Power Derating**



#### **Suggested Mounting Procedures**



- 1. Make sure that the devices are mounted on flat surfaces (.001" under the device) to optimize the heat transfer.
- 2. Position device on mounting surface and solder in place using an indalloy type or a 60/40 type solder.
- Solder leads in place using a 60/40 type solder with a controlled temperature iron (700°F).

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What'll we think of next?

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